



SANYO Semiconductors

DATA SHEET

LV5609LP

Bi-CMOS LSI
For CCD
Vertical Clock Driver

Overview

The LV5609LP is vertical clock driver for CCD.

Functions

- Ternary output ×2ch
- Binary output ×2ch
- SHT output ×1ch
- Output ON resistance : 30Ω typ

Specifications

Absolute Maximum Ratings at Ta = 25°C, V_{SS} = V_M = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max		6	V
	V _H max		20	V
	V _L max		-10	V
	V _H -V _L max		24	V
Allowable power dissipation	P _d max	with specified substrate *	0.8	W
Operating temperature	T _{opr}		-20 to +80	°C
Storage temperature	T _{stg}		-40 to +125	°C

* : Specified substrate : 40×50×0.8mm³, glass epoxy four-layer (2S2P) board

Allowable Operating Ratings at Ta = 25°C, V_{SS} = V_M = 0V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply voltage	V _{DD}		2.0	3.3	5.5	V
	V _H			15	17	V
	V _L		-8.5	-7.5	-4	V
	V _H -V _L				23.5	V
CMOS input High voltage	V _{INH}		0.8V _{DD}		V _{DD}	V
CMOS input Low voltage	V _{INL}		-0.1		0.4	V

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LV5609LP

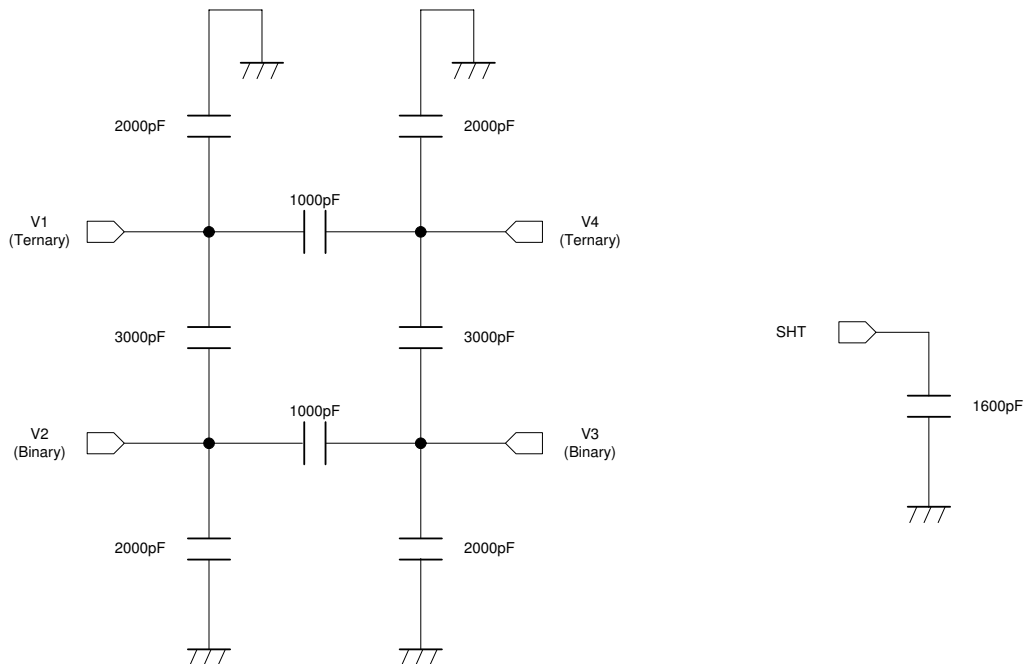
Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{DD} = 3.3\text{V}$, $V_{SS} = 0\text{V}$, $V_H = 15\text{V}$, $V_L = -7.5\text{V}$, $V_M = 0\text{V}$,

Unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Static current drain	I_{DD}	V_{DD} pin			1	μA
	I_H	V_H pin			10	μA
	I_L	V_L pin			1	μA
Dynamic current drain	I_{DD}	V_{DD} pin See *1 and *2.			1	mA
	I_H	V_H pin See *1 and *2.		2.4	4.5	mA
	I_L	V_L pin See *1 and *2.		3	5	mA
Output ON resistance	R_L	$I_O = +10\text{mA}$		20	30	Ω
	R_M	$I_O = \pm 10\text{mA}$		30	45	Ω
	R_H	$I_O = -10\text{mA}$		30	40	Ω
	R_{SHT}	$I_O = -10\text{mA}$		30	40	Ω
Propagation delay time	T_{PLM}	No load			200	ns
	T_{PMH}	No load			200	ns
	T_{PLH}	No load			200	ns
	T_{PML}	No load			200	ns
	T_{PHM}	No load			200	ns
	T_{PHL}	No load			200	ns
Rise time	T_{TLM}	$V_L \rightarrow V_M$ V_1, V_3 See *1.			800	ns
		$V_L \rightarrow V_M$ V_2, V_4 See *1.			800	ns
	T_{TMH}	$V_M \rightarrow V_L$ V_1, V_3 See *1.			800	ns
	T_{TLH}	$V_L \rightarrow V_H$ SHT See *1.			200	ns
Fall time	T_{TML}	$V_M \rightarrow V_L$ V_1, V_3 See *1.			800	ns
		$V_M \rightarrow V_L$ V_2, V_4 See *1.			800	ns
	T_{THM}	$V_H \rightarrow V_M$ V_1, V_3 See *1.			800	ns
	T_{THL}	$V_H \rightarrow V_L$ SHT See *1.			200	ns

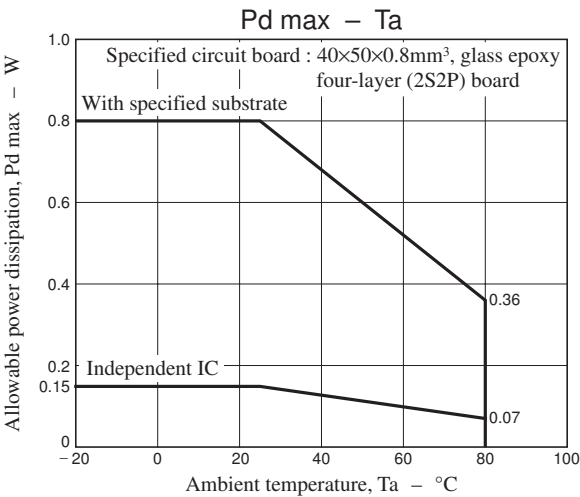
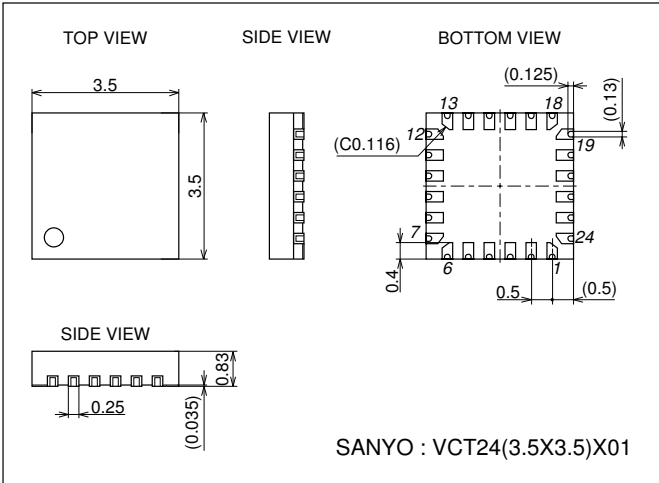
*1 : Refer to the CCD equivalent load shown below.

*2 : Refer to the timing waveform on Page 7.

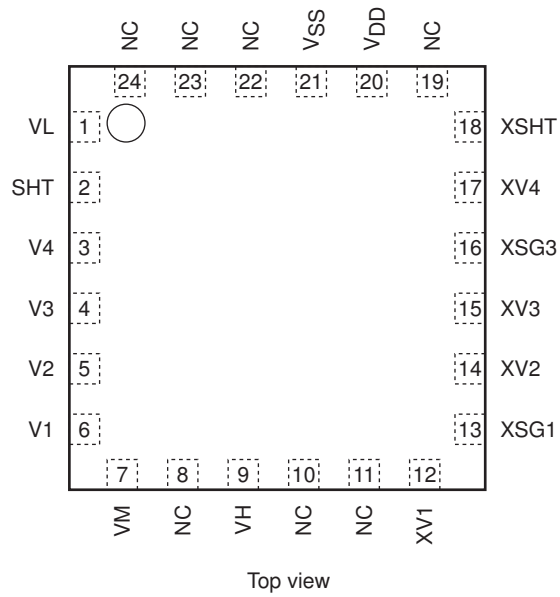


Package Dimensions

unit : mm (typ)
3322



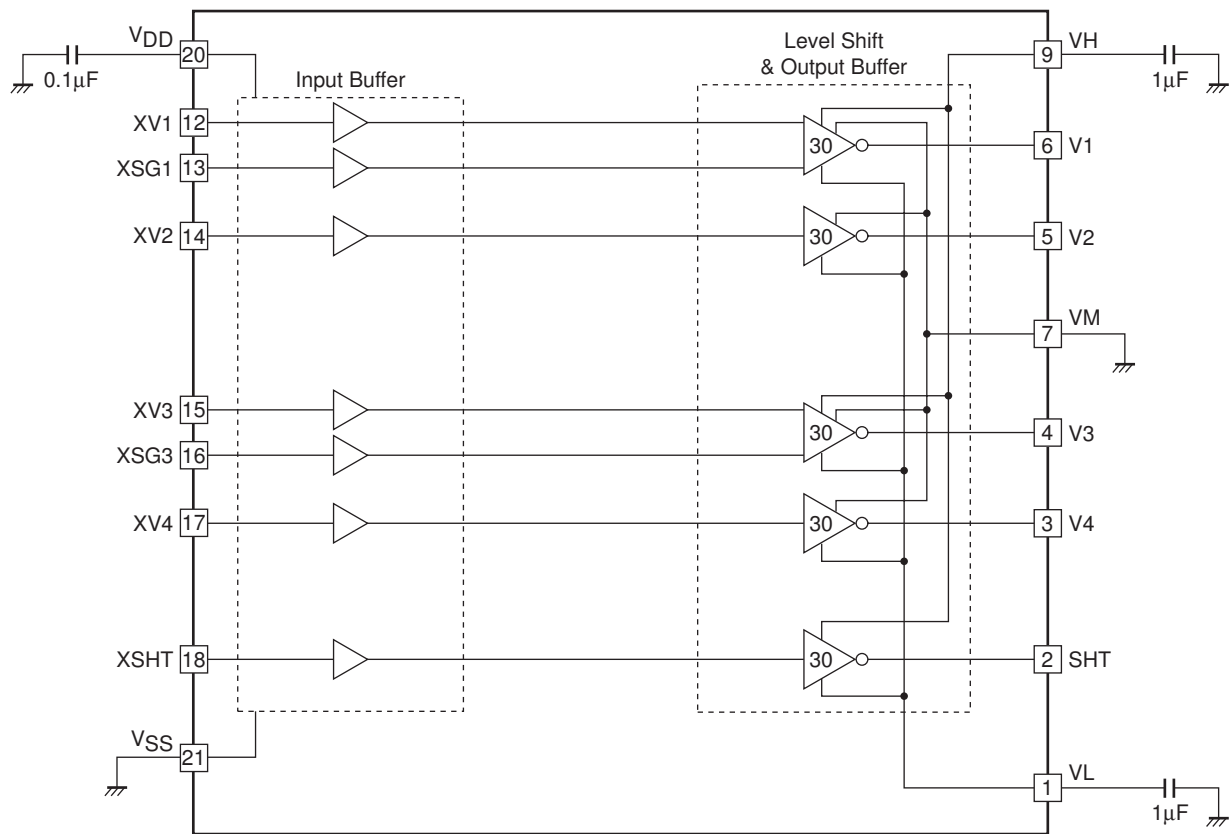
Pin Assignment



Pin Function

Pin No.	Name	Mode
1	VL	Lo power for output (-7.5V system)
2	SHT	Level shift output (binary VH, VL)
3	V4	Level shift output (binary VM, VL)
4	V3	Level shift output (ternary VH, VM, VL)
5	V2	Level shift output (binary VM, VL)
6	V1	Level shift output (ternary VH, VM, VL)
7	VM	GND for output
8	NC	
9	VH	Hi power supply for output (15V system)
10	NC	
11	NC	
12	XV1	V1 transfer pulse input
13	XSG1	V1 read pulse input
14	XV2	V2 transfer pulse input
15	XV3	V3 transfer pulse input
16	XSG3	V3 read pulse input
17	XV4	V4 transfer pulse input
18	XSHT	SHT pulse input
19	NC	
20	V _{DD}	Power supply for input buffer (3.3V system)
21	V _{SS}	GND for input buffer
22	NC	
23	NC	
24	NC	

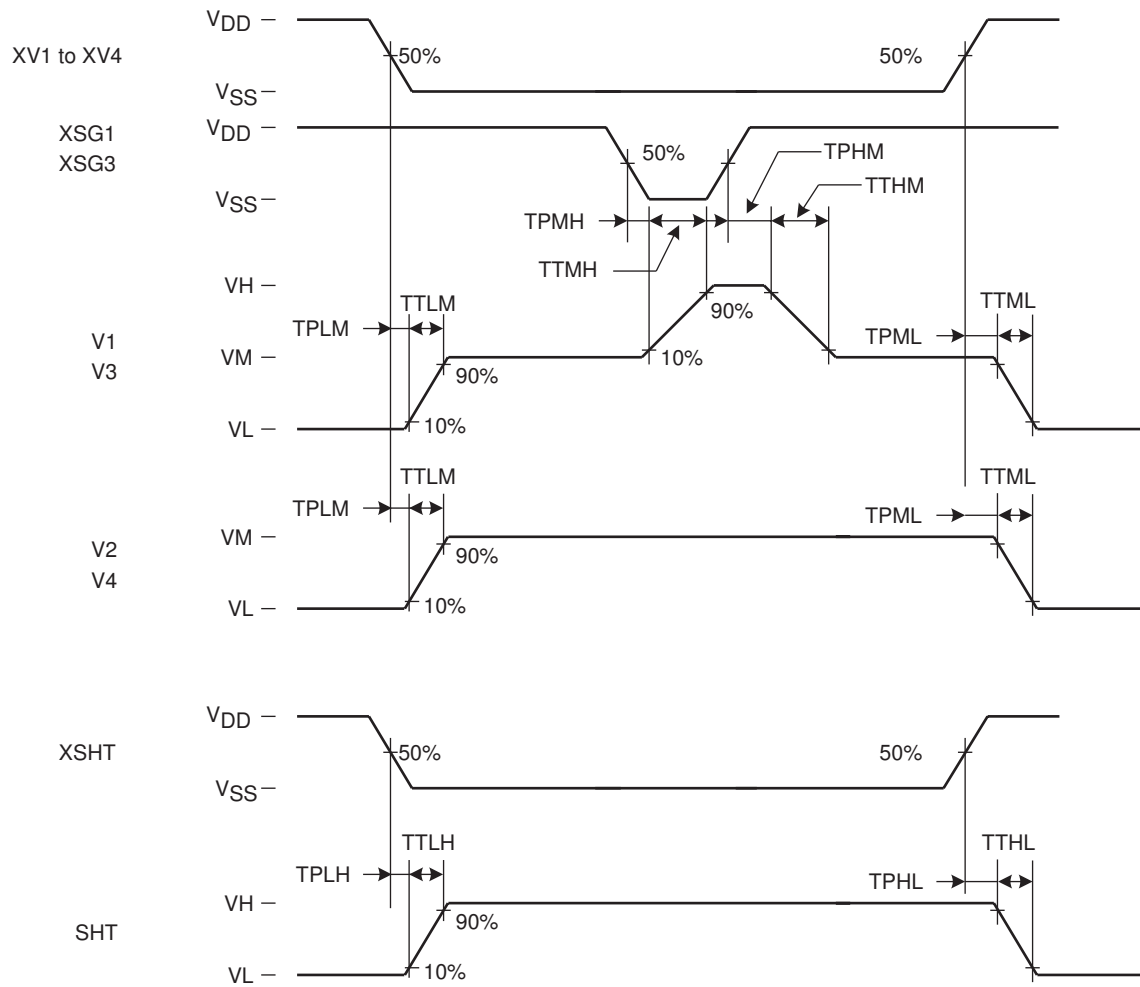
Block Diagram



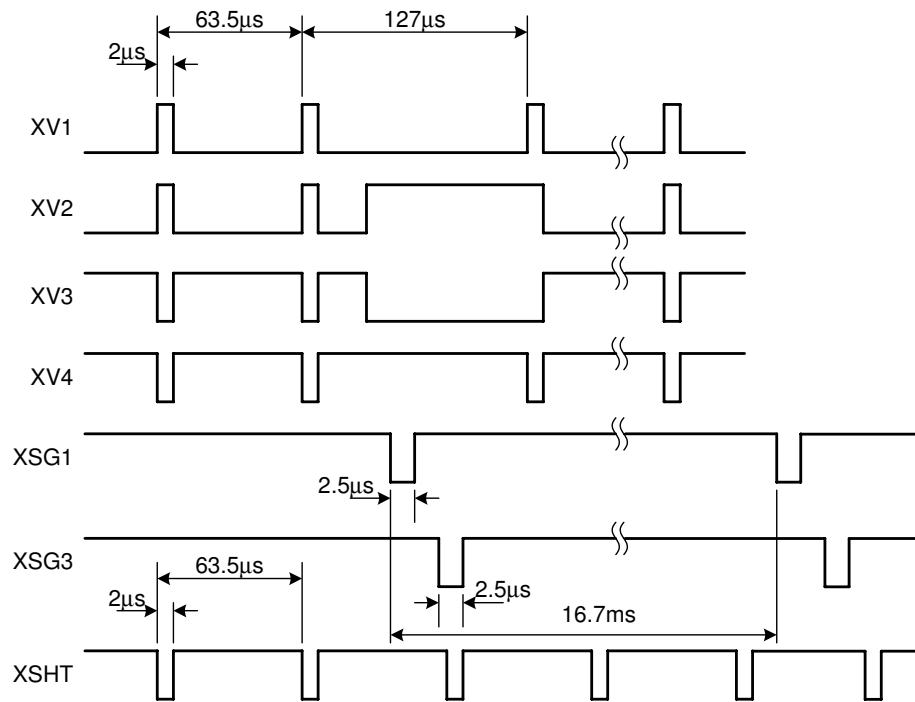
Logical Function Table

Input				Output		
XV1 XV3	XSG1 XSG3	XV2 XV4	XSHT	V1 V3	V2 V4	SHT
L	L	X	X	VH	X	X
L	H	X	X	VM	X	X
H	L	X	X	VL	X	X
H	H	X	X	VL	X	X
X	X	L	X	X	VM	X
X	X	H	X	X	VL	X
X	X	X	L	X	X	VH
X	X	X	H	X	X	VL

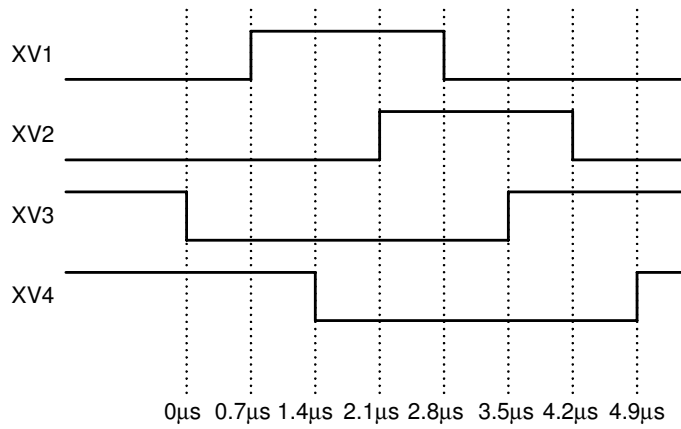
Timing Chart



CCD Equivalent Load Measurement Timing Waveform



Enlarged View of overlapped portion



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